Input/Output Full Swing Low Supply Current **CMOS Operational Amplifiers**

BU7241G BU7241SG BU7242xxx BU7242Sxxx BU7244xx BU7244Sxx

General Description

BU7241G, BU7242xxx, BU7244xx are CMOS operational amplifier of the input/output full swing low voltage operation. Also, BU7241SG, BU7242Sxxx, BU7244Sxx which expanded the operating temperature range perform a lineup. It is most suitable for a sensor amplifier and a battery-powered equipment to have a low input bias current, the characteristic of the low supply current.

Features

- Operable with Low Voltage
- Operable Input-Output Full Swing
- Wide Temperature Range
- Low Supply Current
- Low Input Bias Current

Applications

- Sensor Amplifier
- **Battery Powered Equipment**
- Portable Equipment
- Consumer Equipment

Simplified Schematic

Key Specifications

- Operating Supply Voltage Range:
- +1.8V to +5.5V **Operating Temperature Range:** BU7241G, BU7242xxx, BU7244xx -40°C to +85°C BU7241SG, BU7242Sxxx, BU7244Sxx -40°C to +105°C Supply Current: BU7241, BU7241S 70µA (Typ) BU7242, BU7242S 180µA (Typ) BU7244, BU7244S 360µA (Typ) Input Offset Current: 1pA (Typ) Input Bias Current: 1pA (Typ) Packages W(Typ) x D(Typ) x H(Max) SSOP5 2.90mm x 2.80mm x 1.25mm SOP8 5.00mm x 6.20mm x 1.71mm MSOP8 2.90mm x 4.00mm x 0.90mm VSON008X2030 2.00mm x 3.00mm x 0.60mm
 - SOP14 SSOP-B14

8.70mm x 6.20mm x 1.71mm 5.00mm x 6.40mm x 1.35mm

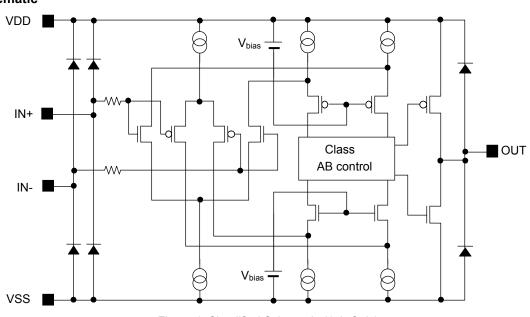
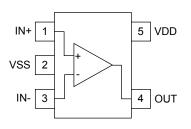


Figure 1. Simplified Schematic (1ch Only)

OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays.

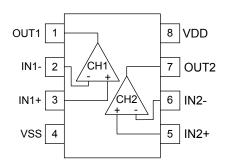
Pin Configuration

BU7241G, BU7241SG : SSOP5



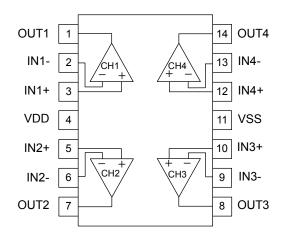
Pin No.	Pin Name
1	IN+
2	VSS
3	IN-
4	OUT
5	VDD

BU7242F, BU7242SF : SOP8 BU7242FVM, BU7242SFVM : MSOP8 BU7242NUX, BU7242SNUX : VSON008X2030



Pin No.	Pin Name				
1	OUT1				
2	IN1-				
3	IN1+				
4	VSS				
5	IN2+				
6	IN2-				
7	OUT2				
8	VDD				

BU7244F, BU7244SF : SOP14 BU7244FV, BU7244SFV : SSOP-B14



Pin No.	Pin Name
1	OUT1
2	IN1-
3	IN1+
4	VDD
5	IN2+
6	IN2-
7	OUT2
8	OUT3
9	IN3-
10	IN3+
11	VSS
12	IN4+
13	IN4-
14	OUT4

Package									
SSOP5	SOP8	VSON008X2030	MSOP8	SOP14	SSOP-B14				
BU7241G BU7241SG	BU7242F BU7242SF	BU7242NUX BU7242SNUX	BU7242FVM BU7242SFVM	BU7244F BU7244SF	BU7244FV BU7244SFV				

Ordering Information

В	U	7	2	4	Х	Х	х	Х	х	-
BU72 BU72 BU72 BU72 BU72	Numbe 241G 241SG 242xxx 242Sxx 242Sxx 244xx 244Sxx	x				G F FV FVN	: S0 : S9 1: M	SOP5 DP8, SC SOP-B1 SOP8 SON008	4	=

ΧХ

Packaging and forming specification E2: Embossed tape and reel (SOP8/SOP14/SSOP-B14) TR: Embossed tape and reel (SSOP5/MSOP8/VSON008X2030)

Line-up

Operating Temperature Range	Channels	Pac	kage	Orderable Part Number
	1ch	SSOP5	Reel of 3000	BU7241G-TR
		SOP8	Reel of 2500	BU7242F-E2
-40°C to +85°C	2ch	MSOP8	Reel of 3000	BU7242FVM-TR
-40 C 10 +65 C		VSON008X2030	Reel of 4000	BU7242NUX-TR
	1.00	SOP14	Reel of 2500	BU7244F-E2
	4ch		Reel of 2500	BU7244FV-E2
	1ch	SSOP5	Reel of 3000	BU7241SG-TR
		SOP8	Reel of 2500	BU7242SF-E2
10°C to 1105°C	2ch	MSOP8	Reel of 3000	BU7242SFVM-TR
-40°C to +105°C		VSON008X2030	Reel of 4000	BU7242SNUX-TR
	1.00	SOP14	Reel of 2500	BU7244SF-E2
	4ch	SSOP-B14	Reel of 2500	BU7244SFV-E2

Absolute Maximum Ratings ($T_A=25^{\circ}C$)

Deremeter		Curren el	Rating					
Parameter		Symbol	BU7241G	BU7242xxx	BU7244xx	Unit		
Supply Voltage	VDD-VSS			+7		V		
		SSOP5	0.54 ^(Note 1,7)	-	-			
		SOP8	-	0.55 ^(Note 2,7)	-			
	-	MSOP8	-	0.47 ^(Note 3,7)	-			
Power Dissipation	PD	VSON008X2030	-	0.41 ^(Note 4,7)	-	W		
		SOP14	-	-	0.45 ^(Note 5,7)			
		SSOP-B14			0.70 ^(Note 6,7)			
Differential Input /oltage ^(Note 8)		V _{ID}		VDD - VSS		V		
nput Common-mode /oltage		VICM	(VSS	6 - 0.3) to (VDD -	+ 0.3)	V		
nput Current (Note 9)		lı –		±10		mA		
Operating Supply /oltage Range		V _{opr}		+1.8 to +5.5		V		
Operating Temperature Range		T _{opr}		-40 to +85		°C		
Storage Temperature Range		T _{stg}		-55 to +125		°C		
Maximum Junction Temperature		T _{Jmax}		+125		°C		

(Note 1) To use at temperature above $T_A=25^{\circ}C$ reduce 5.4mW/°C.

(Note 2) To use at temperature above $T_A=25^{\circ}C$ reduce $5.5mW/^{\circ}C$.

(Note 3) To use at temperature above $T_A=25^{\circ}C$ reduce $4.7mW/^{\circ}C$.

(Note 4) To use at temperature above $T_A=25^{\circ}C$ reduce 4.1mW/°C.

(Note 5) To use at temperature above T_A=25°C reduce 4.5mW/°C. (Note 6) To use at temperature above T_A=25°C reduce 7.0mW/°C.

(Note 7) Mounted on a FR4 glass epoxy PCB 70mm×70mm×1.6mm (Copper foil area less than 3%).

(Note 8) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input pin voltage is set to more than VSS.

(Note 9) An excessive input current will flow when input voltages of more than VDD+0.6V or less than VSS-0.6V are applied.

The input current can be set to less than the rated current by adding a limiting resistor.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Absolute Maximum Ratings (T_A=25°C) - continued

Deremeter	Symbol		Rating						
Parameter		Symbol	BU7241SG	BU7242Sxxx	BU7244Sxx	Unit			
Supply Voltage		VDD-VSS		+7					
		SSOP5	0.54 ^(Note 10,16)	-	-				
		SOP8	-	0.55 ^(Note 11,16)	-				
	-	MSOP8	-	0.47 ^(Note 12,16)	-				
Power Dissipation	PD	VSON008X2030	-	0.41 ^(Note 13,16)	-	W			
		SOP14	-	-	0.45 ^(Note 14,16)				
		SSOP-B14			0.70 ^(Note 15,16)				
Differential Input Voltage ^(Note 17)		V _{ID}		VDD - VSS		V			
Input Common-mode Voltage		V _{ICM}	(VSS	S - 0.3) to (VDD +	· 0.3)	V			
Input Current (Note 18)		l _l		±10		mA			
Operating Supply Voltage Range		V _{opr}		+1.8 to +5.5		V			
Operating Temperature Range		T _{opr}		-40 to +105		°C			
Storage Temperature Range		T _{stg}		-55 to +125		°C			
Maximum Junction Temperature		T _{Jmax}		+125		°C			

(Note 10) To use at temperature above $T_A=25^{\circ}C$ reduce 5.4mW/°C.

(Note 11) To use at temperature above $T_A=25^{\circ}C$ reduce 5.5mW/°C.

(Note 12) To use at temperature above $T_A=25^{\circ}C$ reduce 4.7mW/°C.

(Note 13) To use at temperature above $T_A=25^{\circ}C$ reduce 4.1mW/°C.

(Note 14) To use at temperature above $T_A=25^{\circ}C$ reduce 4.5mW/°C.

(Note 15) To use at temperature above $T_A=25^{\circ}C$ reduce 7.0mW/°C.

(Note 16) Mounted on a FR4 glass epoxy PCB 70mm×70mm×1.6mm (Copper foil area less than 3%).

(Note 17) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input pin voltage is set to more than VSS.

(Note 18) An excessive input current will flow when input voltages of more than VDD+0.6V or less than VSS-0.6V are applied. The input current can be set to less than the rated current by adding a limiting resistor.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Electrical Characteristics

OBU7241 (Unless otherwise specified VDD=+3V, VSS=0V, T_A=25°C)

		Temperature	,	Limit		11	Qualitieree
Parameter	Symbol	Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 19, 20)	Vio	25°C	-	1	9	mV	VDD=1.8 to 5.5V
Input Offset Current (Note 19)	I _{IO}	Full range 25°C	-	- 1	10 -	pА	-
Input Bias Current (Note 19)	I _B	25°C	-	1	-	pА	-
Supply Current (Note 20)	I _{DD}	25°C Full range	-	70	150 250	μA	R _L =∞, A _V =0dB IN+=1.5V
Maximum Output Voltage(High)	V _{OH}	25°C	VDD-0.1	-	-	V	R _L =10kΩ
Maximum Output Voltage(Low)	V _{OL}	25°C	-	-	VSS+0.1	V	$R_L=10k\Omega$
Large Signal Voltage Gain	Av	25°C	70	95	-	dB	R _L =10kΩ
Input Common-mode Voltage Range	V _{ICM}	25°C	0	-	3	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	45	60	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	60	80	-	dB	-
Output Source Current (Note 21)	ISOURCE	25°C	4	10	-	mA	OUT=VDD-0.4V
Output Sink Current (Note 21)	I _{SINK}	25°C	5	12	-	mA	OUT=VSS+0.4V
Slew Rate	SR	25°C	-	0.4	-	V/µs	C∟=25pF
Gain Bandwidth	GBW	25°C	-	0.9	-	MHz	C _L =25pF, A _V =40dB
Phase Margin	θ	25°C	-	50	-	deg	C _L =25pF, A _V =40dB
Total Harmonic Distortion + Noise	THD+N	25°C	-	0.05	-	%	OUT=0.8V _{P-P} , f=1kHz

(Note 19) Absolute value

(Note 20) Full range: BU7241: T_A=-40°C to +85°C BU7241S: T_A=-40°C to +105°C

(Note 21) Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

Electrical Characteristics - continued

OBU7242 (Unless otherwise specified VDD=+3V, VSS=0V, T_A=25°C)

Parameter	Symbol	Temperature		Limit		Unit	Conditions
Parameter	Symbol	Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 22, 23)	VIO	25°C	-	1	9	mV	VDD=1.8 to 5.5V
input Oliset voltage	VIO	Full range	-		10	111V	OUT=VDD/2
Input Offset Current (Note 22)	I _{IO}	25°C	-	1	-	pА	-
Input Bias Current (Note 22)	I _B	25°C	-	1	-	pА	-
Supply Current (Note 23)		25°C	-	180	360		R _L =∞, All Op-Amps
Supply Current *	I _{DD}	Full range	-	-	600	μA	A _V =0dB, IN+=1.5V
Maximum Output Voltage(High)	V _{OH}	25°C	VDD-0.1	-	-	V	R∟=10kΩ
Maximum Output Voltage(Low)	V _{OL}	25°C	-	-	VSS+0.1	V	$R_L=10k\Omega$
Large Signal Voltage Gain	A_{V}	25°C	70	95	-	dB	R_L =10k Ω
Input Common-mode Voltage Range	V _{ICM}	25°C	0	-	3	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	45	60	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	60	80	-	dB	-
Output Source Current (Note 24)	ISOURCE	25°C	4	10	-	mA	OUT=VDD-0.4V
Output Sink Current (Note 24)	I _{SINK}	25°C	5	12	-	mA	OUT=VSS+0.4V
Slew Rate	SR	25°C	-	0.4	-	V/µs	C _L =25pF
Gain Bandwidth	GBW	25°C	-	0.9	-	MHz	C_L =25pF, A_V =40dB
Phase Margin	θ	25°C	-	50	-	deg	C _L =25pF, A _V =40dB
Total Harmonic Distortion + Noise	THD+N	25°C	-	0.05	-	%	OUT=0.8 V _{P-P} , f=1kHz
Channel Separation	CS	25°C	-	100	-	dB	A _V =40dB, OUT=1Vrm

(Note 22) Absolute value

(Note 23) Full range: BU7242: T_A =-40°C to +85°C BU7242S: T_A =-40°C to +105°C

(Note 24) Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

Electrical Characteristics - continued

OBU7244 (Unless otherwise specified VDD=+3V, VSS=0V, T_A=25°C)

Parameter	Symbol	Temperature		Limit		Unit	Conditions
Parameter	Symbol	Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 25, 26)	VIO	25°C	-	1	9	mV	VDD=1.8 to 5.5V
input Onset voltage	VIO	Full range	-	-	10	IIIV	OUT=VDD/2
Input Offset Current (Note 25)	I _{IO}	25°C	-	1	-	pА	-
Input Bias Current (Note 25)	Ι _Β	25°C	-	1	-	pА	-
Supply Current (Note 26)	I	25°C	-	360	750	μA	R _L =∞, All Op-Amps
Supply Current	I _{DD}	Full range	-	-	1200	μΑ	A _V =0dB, IN+=1.5V
Maximum Output Voltage(High)	V_{OH}	25°C	VDD-0.1	-	-	V	R∟=10kΩ
Maximum Output Voltage(Low)	V _{OL}	25°C	-	-	VSS+0.1	V	$R_L=10k\Omega$
Large Signal Voltage Gain	Av	25°C	70	95	-	dB	$R_L=10k\Omega$
Input Common-mode Voltage Range	VICM	25°C	0	-	3	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	45	60	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	60	80	-	dB	-
Output Source Current (Note 27)	I _{SOURCE}	25°C	4	10	-	mA	OUT=VDD-0.4V
Output Sink Current (Note 27)	I _{SINK}	25°C	5	12	-	mA	OUT=VSS+0.4V
Slew Rate	SR	25°C	-	0.4	-	V/µs	C _L =25pF
Gain Bandwidth	GBW	25°C	-	0.9	-	MHz	C _L =25pF, A _V =40dB
Phase Margin	θ	25°C	-	50	-	deg	C _L =25pF, A _V =40dB
Total Harmonic Distortion + Noise	THD+N	25°C	-	0.05	-	%	OUT=0.8 V _{P-P} , f=1kHz
Channel Separation	CS	25°C	-	100	-	dB	A _V =40dB, OUT=1Vrm

(Note 25) Absolute value

(Note 26) Full range: BU7244: T_A =-40°C to +85°C BU7244S: T_A =-40°C to +105°C

(Note 27) Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

Description of electrical characteristics

Described below are descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

1. Absolute maximum ratings

Absolute maximum rating items indicate the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

- (1) Supply Voltage (VDD/VSS) Indicates the maximum voltage that can be applied between the VDD terminal and VSS terminal without deterioration or destruction of characteristics of internal circuit.
- (2) Differential Input Voltage (V_{ID})
 Indicates the maximum voltage that can be applied between non-inverting and inverting terminals without damaging the IC.
- (3) Input Common-mode Voltage Range (V_{ICM}) Indicates the maximum voltage that can be applied to the non-inverting and inverting terminals without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.
- (4) Power Dissipation (P_D) Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, P_D is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

2. Electrical characteristics

(1) Input Offset Voltage (V_{IO})

Indicates the voltage difference between non-inverting terminal and inverting terminals. It can be translated into the input voltage difference required for setting the output voltage at 0 V.

- Input Offset Current (I_{IO})
 Indicates the difference of input bias current between the non-inverting and inverting terminals.
- (3) Input Bias Current (I_B) Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias currents at the non-inverting and inverting terminals.
- (4) Supply Current (I_{DD}) Indicates the current that flows within the IC under specified no-load conditions.
- (5) Maximum Output Voltage(High) / Maximum Output Voltage(Low) (V_{OH}/V_{OL}) Indicates the voltage range of the output under specified load condition. It is typically divided into maximum output voltage high and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.
- (6) Large Signal Voltage Gain (A_V)
 Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.
 Av = (Output voltage) / (Differential Input voltage)
- (7) Input Common-mode Voltage Range (V_{ICM})
 Indicates the input voltage range where IC normally operates.
- (8) Common-mode Rejection Ratio (CMRR) Indicates the ratio of fluctuation of input offset voltage when the input common mode voltage is changed. It is normally the fluctuation of DC. CMRR = (Change of Input common-mode voltage)/(Input offset fluctuation)
- (9) Power Supply Rejection Ratio (PSRR) Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC.
 PSRR = (Change of power supply voltage)/(Input offset fluctuation)
- (10) Output Source Current / Output Sink Current (I_{SOURCE}/I_{SINK}) The maximum current that can be output under specific output conditions, it is divided into output source current and output sink current. The output source current indicates the current flowing out of the IC, and the output sink current the current flowing into the IC.
- (11) Slew Rate (SR) Indicates the ratio of the change in output voltage with time when a step input signal is applied.
- (12) Gain Bandwidth (GBW)

The product of the open-loop voltage gain and the frequency at which the voltage gain decreases 6dB/octave.

(13) Phase Margin (θ)

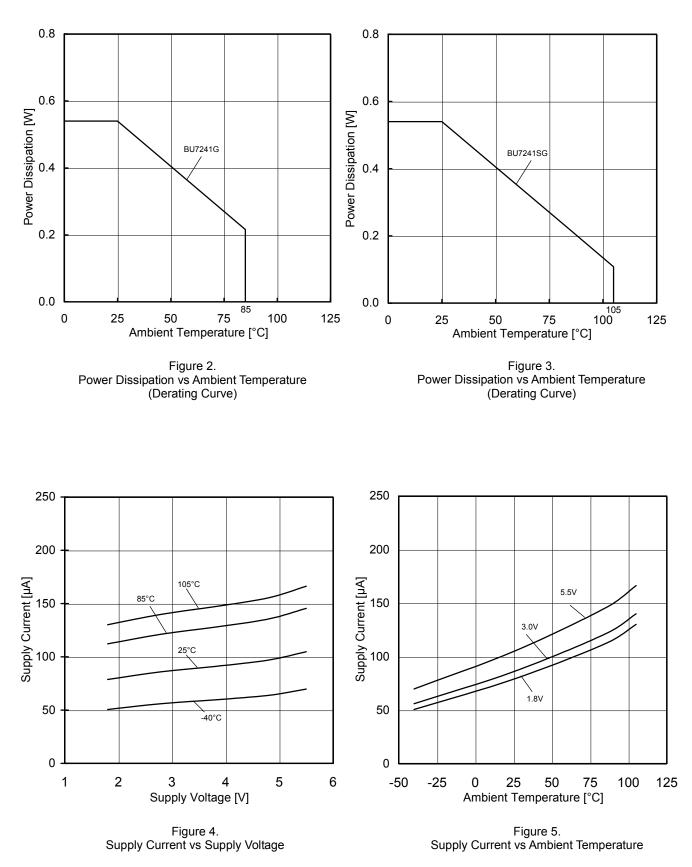
Indicates the margin of phase from 180 degree phase lag at unity gain frequency. (14) Total Harmonic Distortion + Noise (THD+N)

Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.

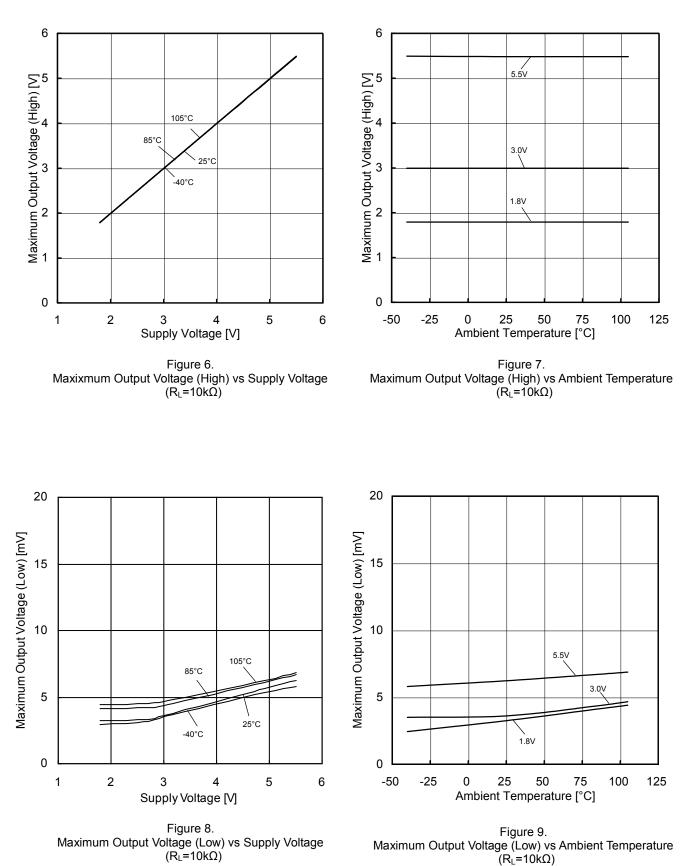
(15) Channel Separation (CS) Indicates the fluctuation in the output voltage of the driven channel with reference to the change of output voltage of the channel which is not driven.

Typical Performance Curves

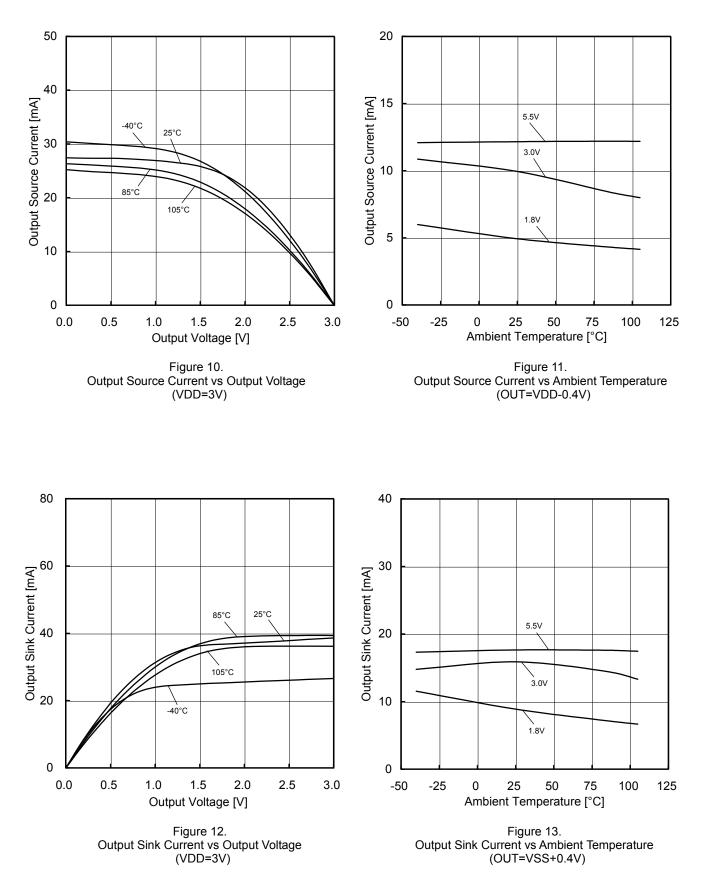
OBU7241G, BU7241SG



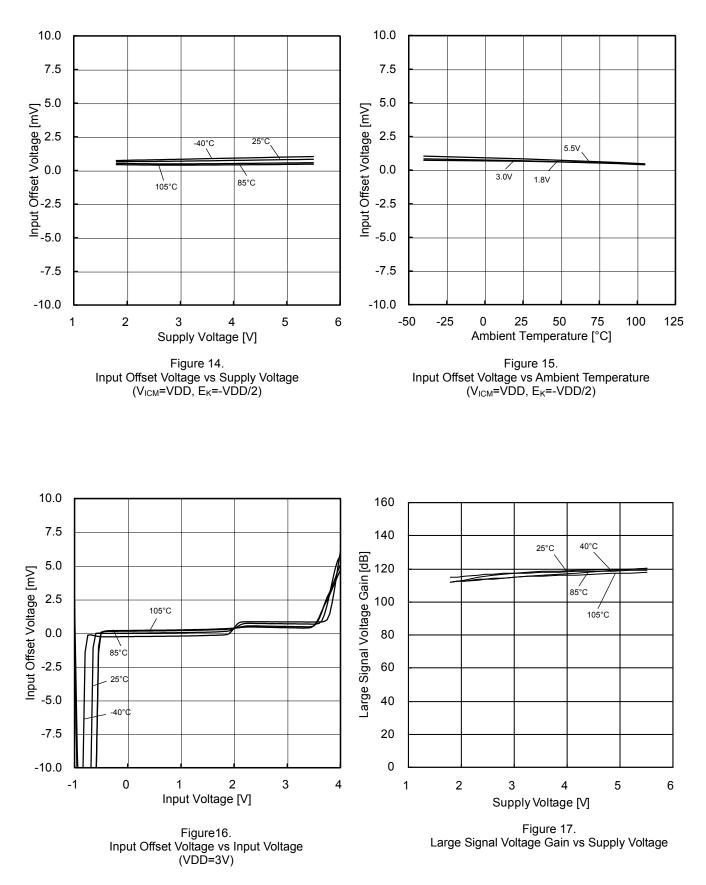
OBU7241G, BU7241SG



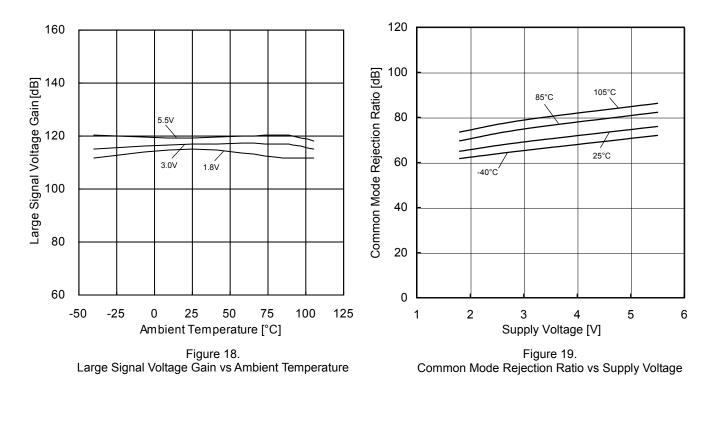
OBU7241G, BU7241SG

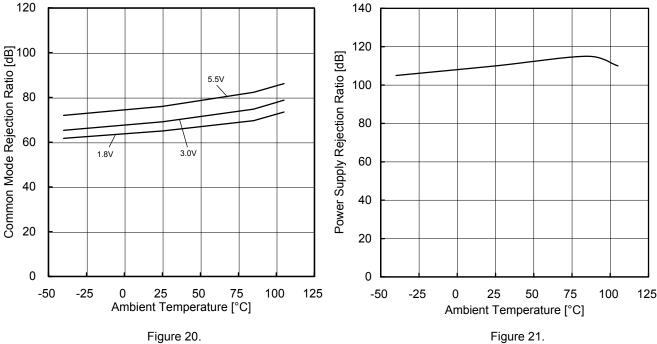


OBU7241G, BU7241SG



OBU7241G, BU7241SG

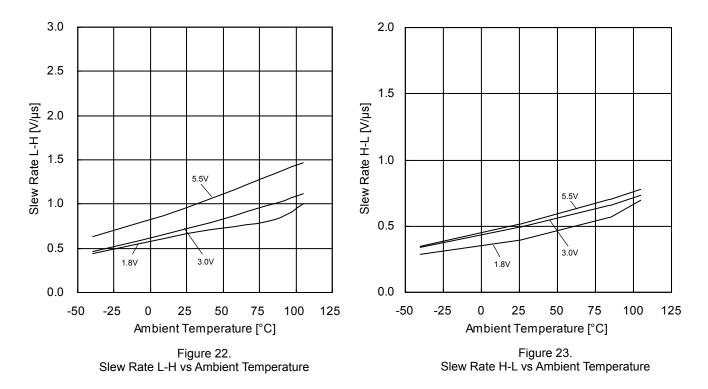




Common Mode Rejection Ratio vs Ambient Temperature

Power Supply Rejection Ratio vs Ambient Temperature

OBU7241G, BU7241SG



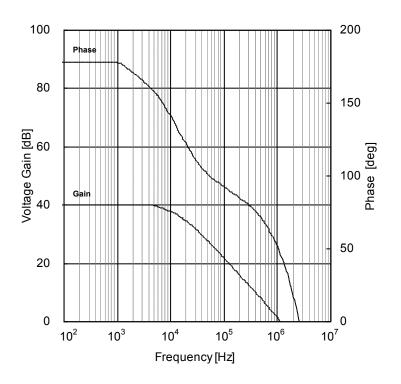
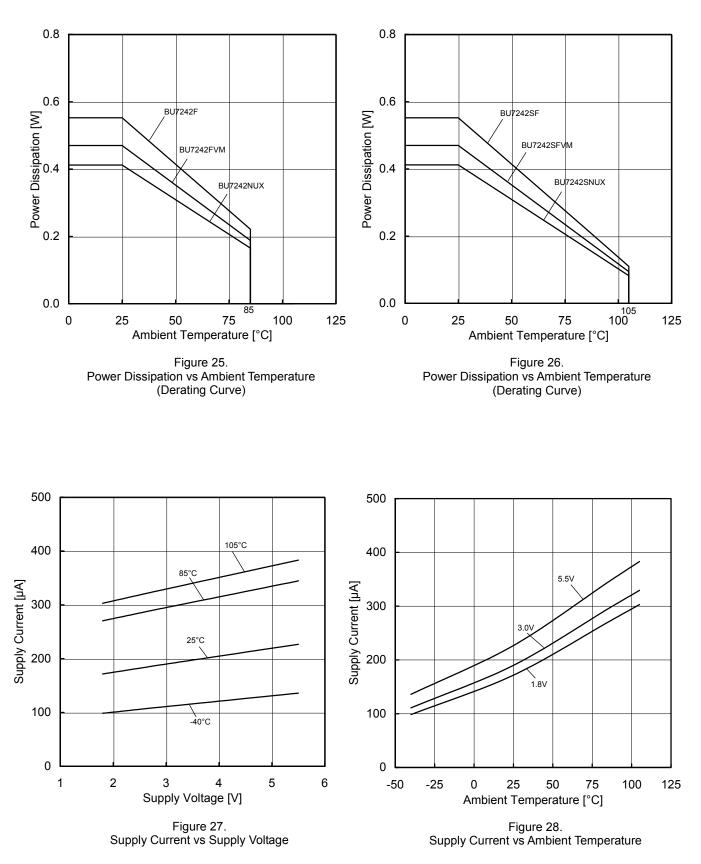
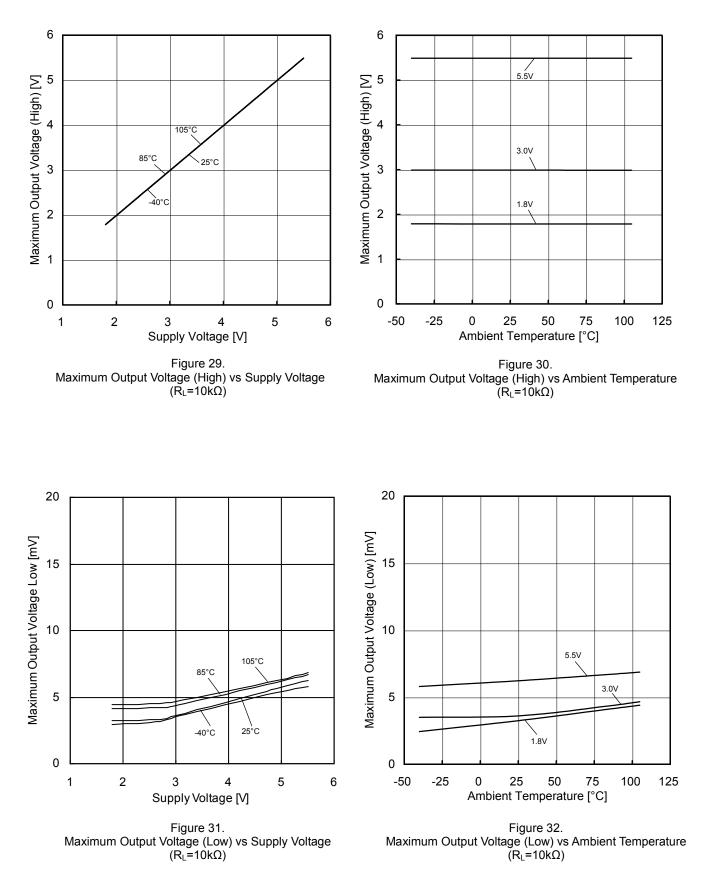


Figure 24. Voltage Gain / Phase vs Frequency

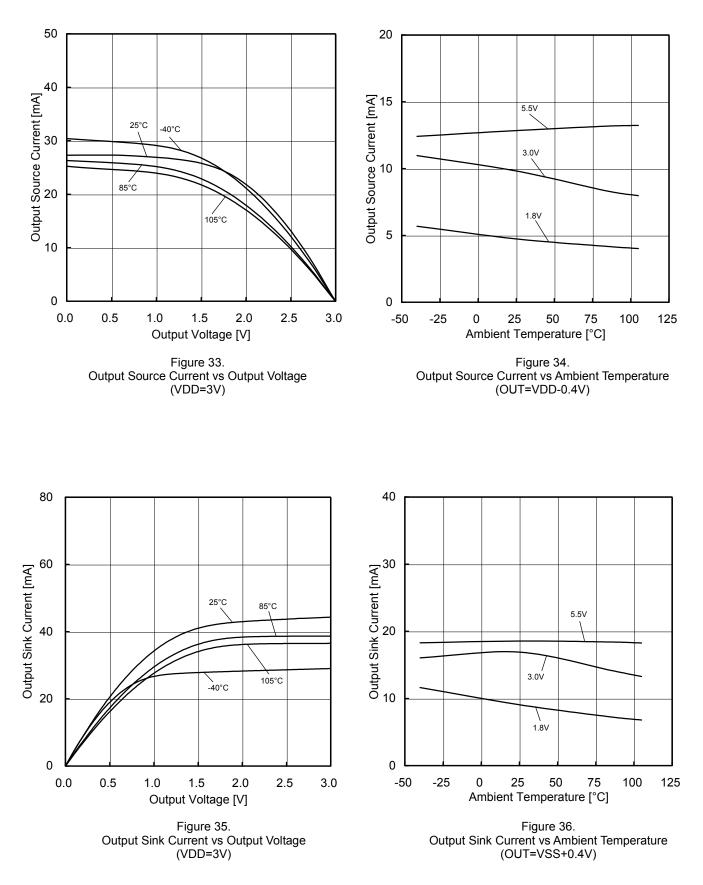
OBU7242xxx, BU7242Sxxx



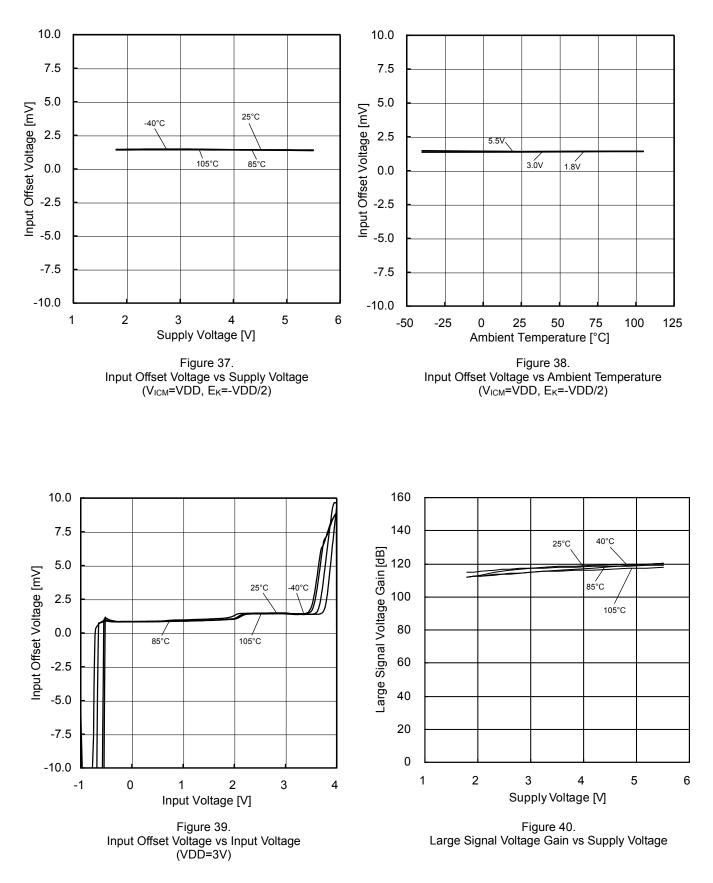
OBU7242xxx, BU7242Sxxx



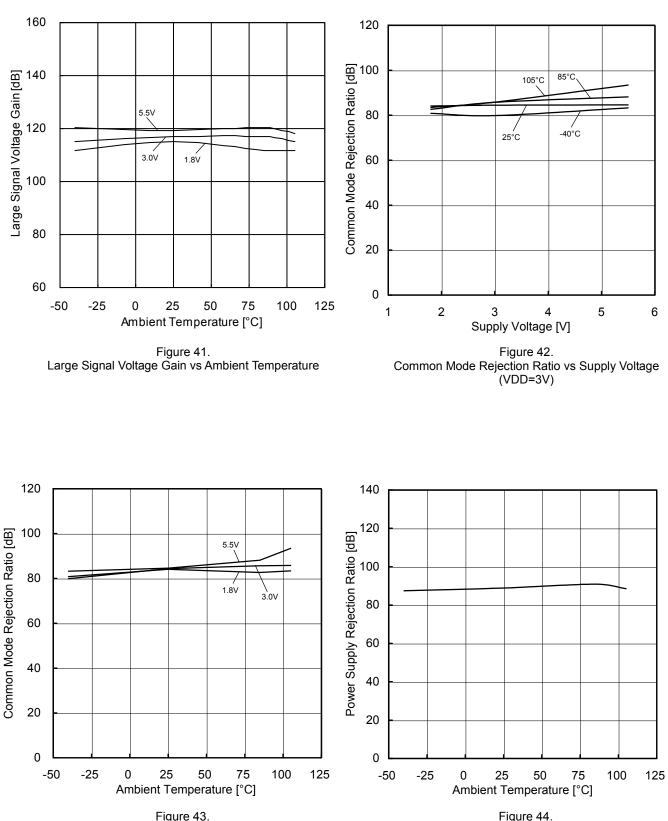
OBU7242xxx, BU7242Sxxx

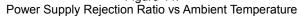


OBU7242xxx, BU7242Sxxx



OBU7242xxx, BU7242Sxxx

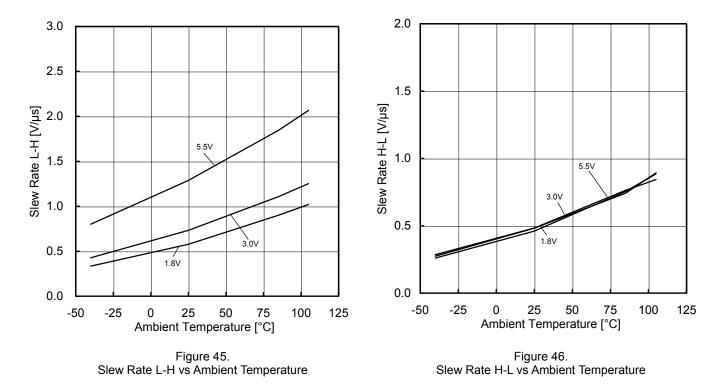




(*)The above characteristics are measurements of typical sample, they are not guaranteed. BU7242xxx: -40°C to +85°C BU7242Sxxx: -40°C to +105°C

Common Mode Rejection Ratio vs Ambient Temperature (VDD=3V)

OBU7242xxx, BU7242Sxxx



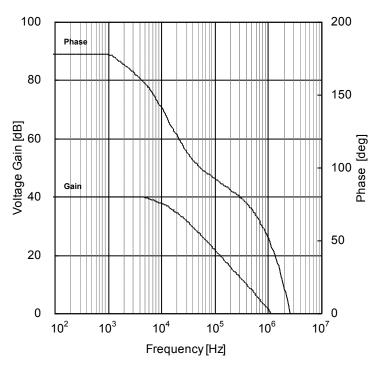
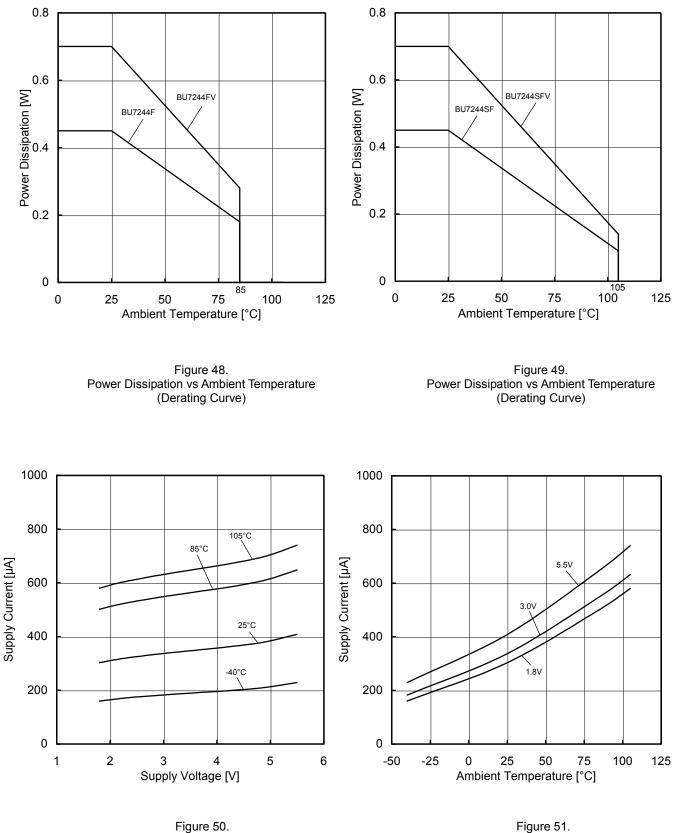


Figure 47. Voltage Gain / Phase vs Frequency

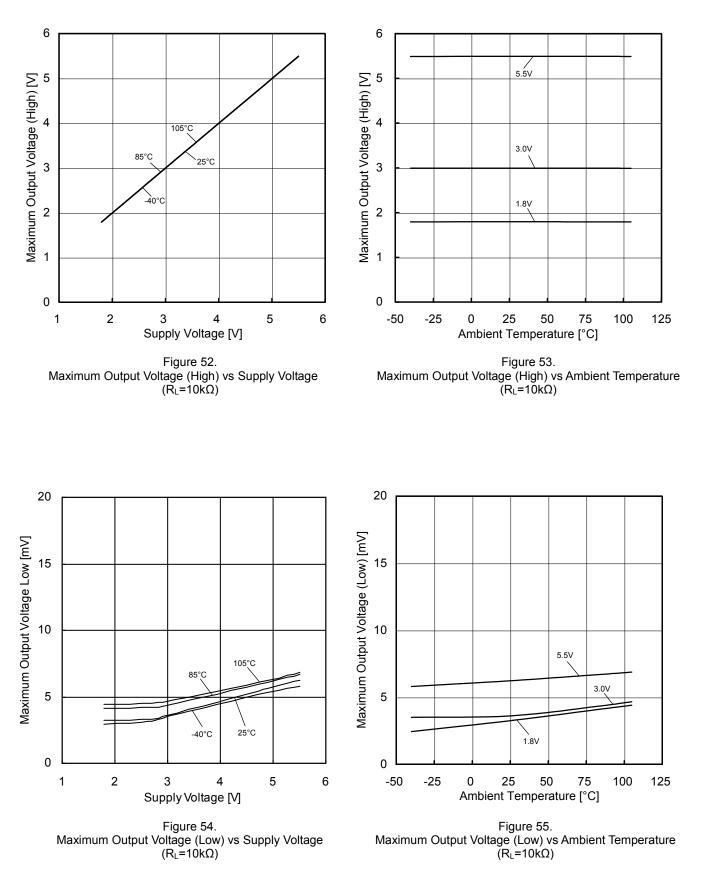
OBU7244xx, BU7244Sxx



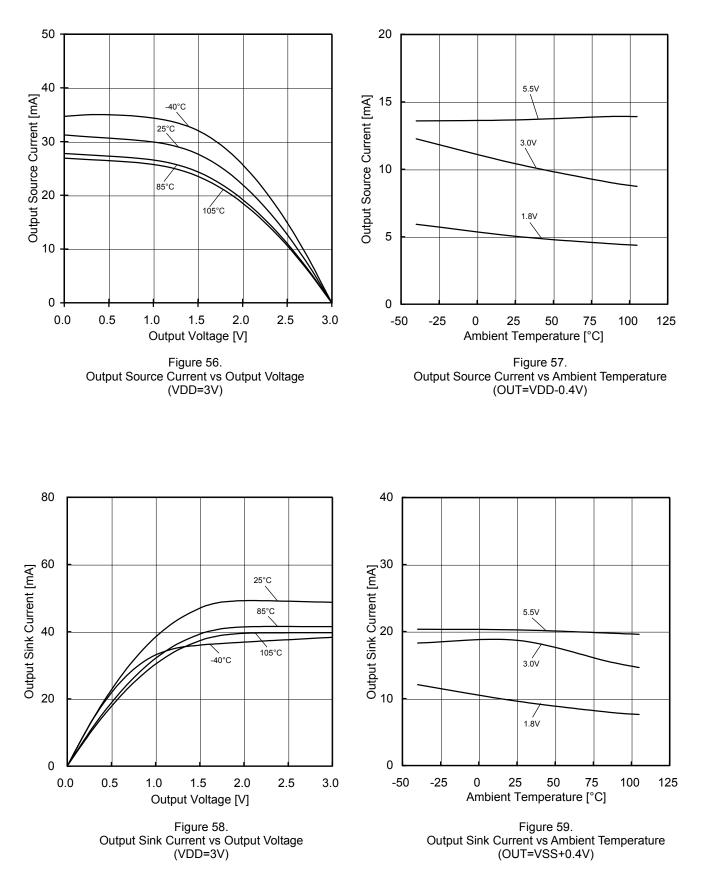
Supply Current vs Supply Voltage

Figure 51. Supply Current vs Ambient Temperature

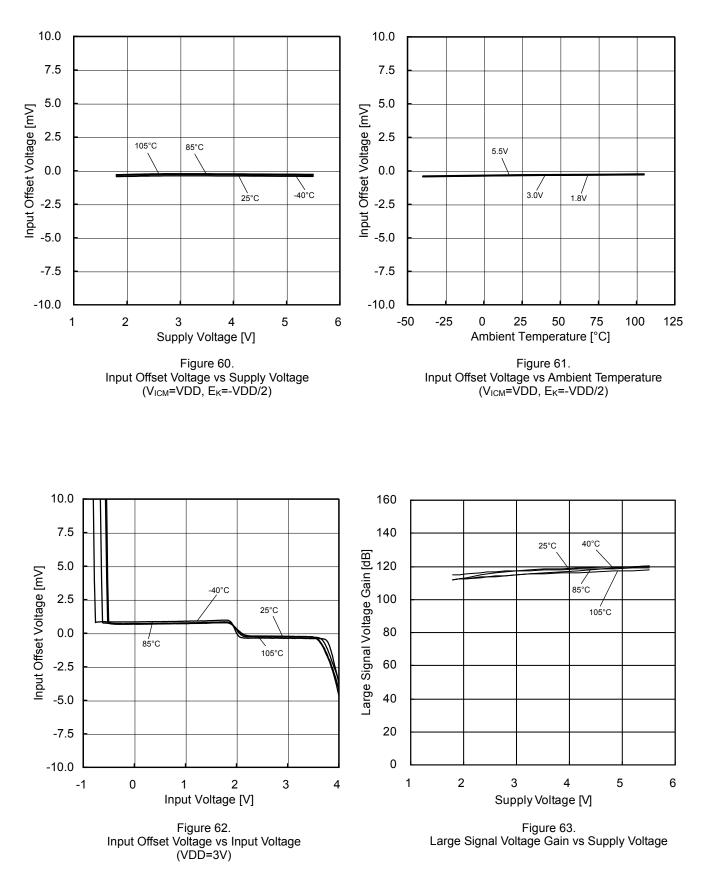
OBU7244xx, BU7244Sxx



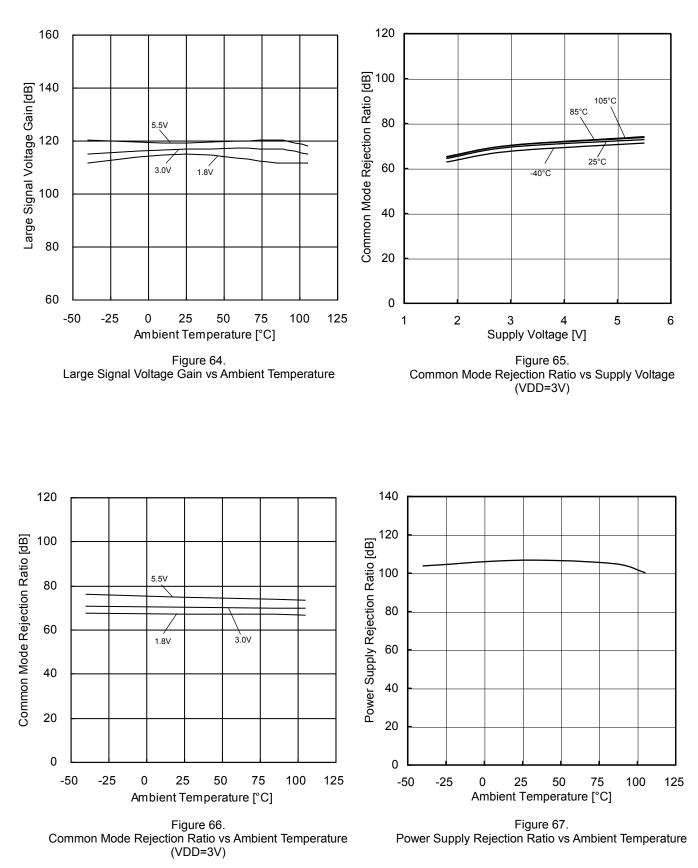
OBU7244xx, BU7244Sxx



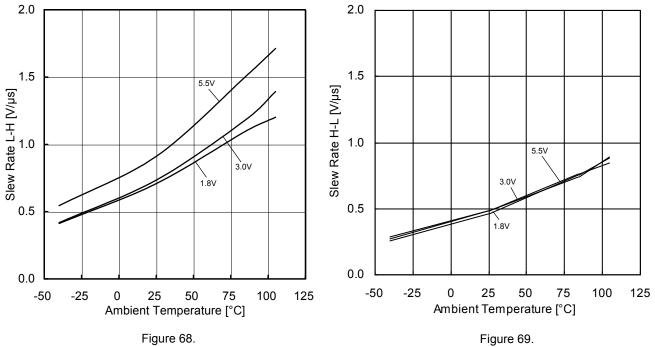
OBU7244xx, BU7244Sxx



OBU7244xx, BU7244Sxx



OBU7244xx, BU7244Sxx



Slew Rate L-H vs Ambient Temperature

Slew Rate H-L vs Ambient Temperature

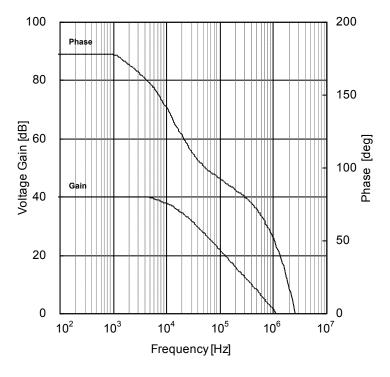


Figure 70. Voltage Gain / Phase vs Frequency

Application Information

NULL method condition for Test Circuit 1

						V	DD, VSS	S, E _κ , V _I	_{см} Unit:V
Parameter	V_{F}	S1	S2	S3	VDD	VSS	Eκ	V _{ICM}	Calculation
Input Offset Voltage	V _{F1}	ON	ON	OFF	3	0	-1.5	3	1
Large Signal Voltage Gain	V_{F2}	- ON	ON	ON	3	0	-0.5	1.5	2
	V _{F3}						-2.5		
Common-mode Rejection Ratio	V_{F4}	ON	ON	OFF	3	0	-1.5	0	3
(Input Common-mode Voltage Range)	V_{F5}		ON	OFF	5	0	-1.5	3	5
Power Supply Rejection Ratio	V_{F6}	ON	ON	OFF	1.8	0	-0.9	0	4
	V_{F7}		UN	OFF	5.5	0	-0.9	U	4

- Calculation -

1. Input Offset Voltage (VIO)

 $V_{IO} = \frac{|V_{F1}|}{1 + R_F/R_S} \quad [V]$

2. Large Signal Voltage Gain (A_V) Av = 20Log $\frac{\Delta}{-}$

 $Av = 20Log \quad \frac{\Delta E_{K} \times (1+R_{F}/R_{S})}{|V_{F2}-V_{F3}|} \quad [dB]$

3. Common-mode Rejection Ratio (CMRR)

$$CMRR=20Log \frac{\Delta V_{ICM} \times (1+R_F/R_S)}{|V_{F4} - V_{F5}|} [dB]$$

4. Power Supply Rejection Ratio (PSRR)

$$\label{eq:PSRR} \begin{split} \text{PSRR} = 20 \text{Log} \; \underline{\Delta \; \text{VDD} \times (1 + R_{\text{F}}/R_{\text{S}})}{|V_{\text{F6}} - V_{\text{F7}}|} \quad [\text{dB}] \end{split}$$

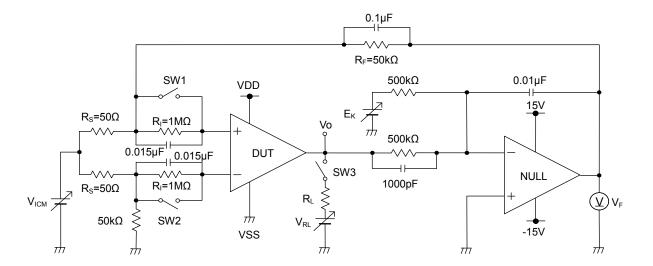
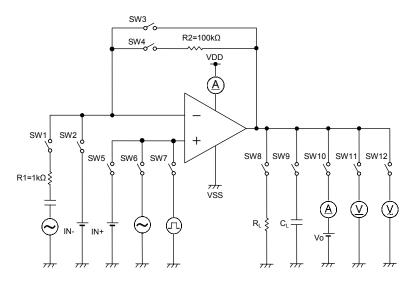


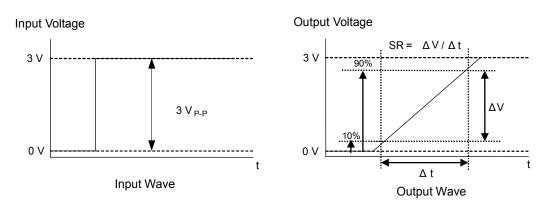
Figure 71. Test Circuit 1 (One Channel Only)

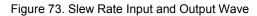
Application Information - continued Switch Condition for Test Circuit 2

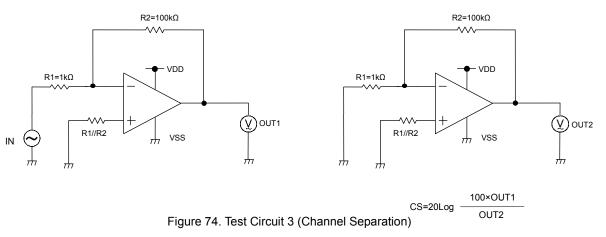
SW No.	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8	SW9	SW10	SW11	SW12
Supply Current	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF
Maximum Output Voltage R_L =10k Ω	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF
Output Current	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF
Slew Rate	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	ON
Gain Bandwidth	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	ON	OFF	OFF	ON





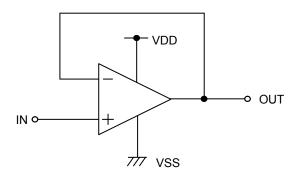


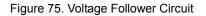




Examples of Circuit

OVoltage Follower





OInverting Amplifier

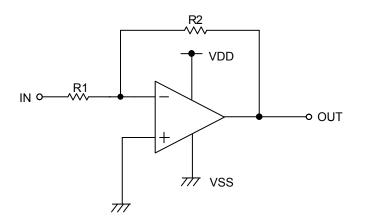


Figure 76. Inverting Amplifier Circuit

ONon-inverting Amplifier

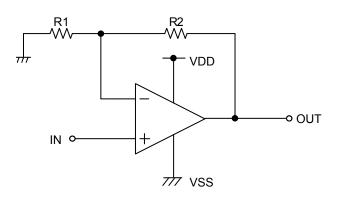


Figure 77. Non-inverting Amplifier Circuit

Voltage gain is 0dB.

Using this circuit, the output voltage (OUT) is configured to be equal to the input voltage (IN). This circuit also stabilizes the output voltage (OUT) due to high input impedance and low output impedance. Computation for output voltage (OUT) is shown below.

OUT=IN

For inverting amplifier, input voltage (IN) is amplified by a voltage gain and depends on the ratio of R1 and R2. The out-of-phase output voltage is shown in the next expression

OUT=-(R2/R1) · IN

This circuit has input impedance equal to R1.

For non-inverting amplifier, input voltage (IN) is amplified by a voltage gain, which depends on the ratio of R1 and R2. The output voltage (OUT) is in-phase with the input voltage (IN) and is shown in the next expression.

Effectively, this circuit has high input impedance since its input side is the same as that of the operational amplifier.

Power Dissipation

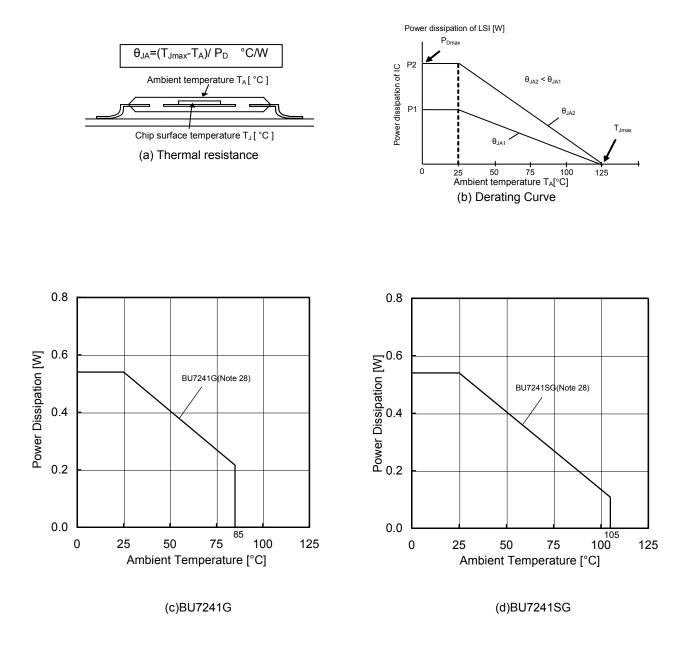
Power dissipation (total loss) indicates the power that the IC can consume at $T_A=25^{\circ}C$ (normal temperature). As the IC consumes power, it heats up, causing its temperature to be higher than the ambient temperature. The allowable temperature that the IC can accept is limited. This depends on the circuit configuration, manufacturing process, and consumable power.

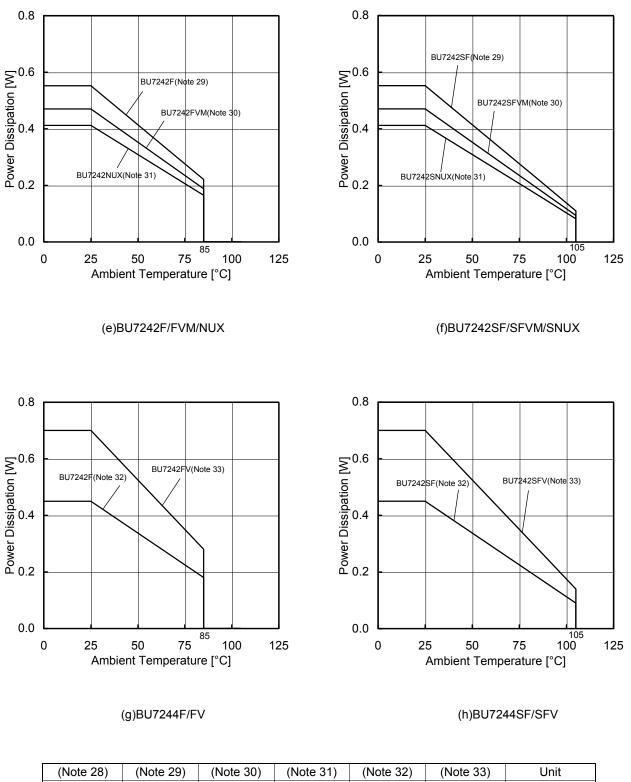
Power dissipation is determined by the allowable temperature within the IC (maximum junction temperature) and the thermal resistance of the package used (heat dissipation capability). Maximum junction temperature is typically equal to the maximum storage temperature. The heat generated through the consumption of power by the IC radiates from the mold resin or lead frame of the package. Thermal resistance, represented by the symbol θ_{JA} °C/W, indicates this heat dissipation capability. Similarly, the temperature of an IC inside its package can be estimated by thermal resistance.

Figure 78(a) shows the model of the thermal resistance of a package. The equation below shows how to compute for the Thermal resistance (θ_{JA}), given the ambient temperature (T_A), maximum junction temperature (T_{Jmax}), and power dissipation (P_D).

$$\theta_{JA} = (T_{Jmax} - T_A) / P_D \circ C/W$$

The Derating curve in Figure 78 (b) indicates the power that the IC can consume with reference to ambient temperature. Power consumption of the IC begins to attenuate at certain temperatures. This gradient is determined by Thermal resistance (θ_{JA}), which depends on the chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc. This may also vary even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 78(c) to 78(h) shows an example of the derating curve for BU7241G, BU7241SG, BU7242xxx, BU7242Sxxx, BU7244xx, BU7244Sxx.





(11010 20)	(11010 20)	(100000)		(1010 02)	(100000)	Onic
5.4	5.5	4.7	4.12	4.5	7.0	mW/°C
When using the unit above $T_A=25^{\circ}$ C, subtract the value above per Celsius degree. Power dissipation is the value						

when FR4 glass epoxy board 70mm × 70mm × 1.6mm (copper foil area less than 3%) is mounted

Figure 78. Thermal Resistance and Derating Curve

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the P_D stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the P_D rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

12. Regarding the Input Pin of the IC

In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

13. Unused Circuits

When there are unused op-amps, it is recommended that they are connected as in Figure 79, setting the non-inverting input terminal to a potential within the Input Common-mode Voltage Range (V_{ICM}). Keep t in V_{ICM}

14. Input Voltage

Applying VDD+0.3V to the input terminal is possible without causing deterioration of the electrical characteristics or destruction. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

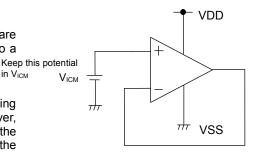


Figure 79. Example of Application Circuit for Unused Op-amp

15. Power Supply(single/dual)

The operational amplifier operates when the voltage supplied is between VDD and VSS. Therefore, the single supply operational amplifiers can be used as dual supply operational amplifiers as well.

16. Output Capacitor

If a large capacitor is connected between the output pin and VSS pin, current from the charged capacitor will flow into the output pin and may destroy the IC when the VDD pin is shorted to ground or pulled down to 0V. Use a capacitor smaller than 0.1uF between output pin and VSS pin.

17. Oscillation by Output Capacitor

Please pay attention to the oscillation by output capacitor and in designing an application of negative feedback loop circuit with these ICs.

18. Latch up

Be careful of input voltage that exceed the VDD and VSS. When CMOS device have sometimes occur latch up and protect the IC from abnormaly noise.

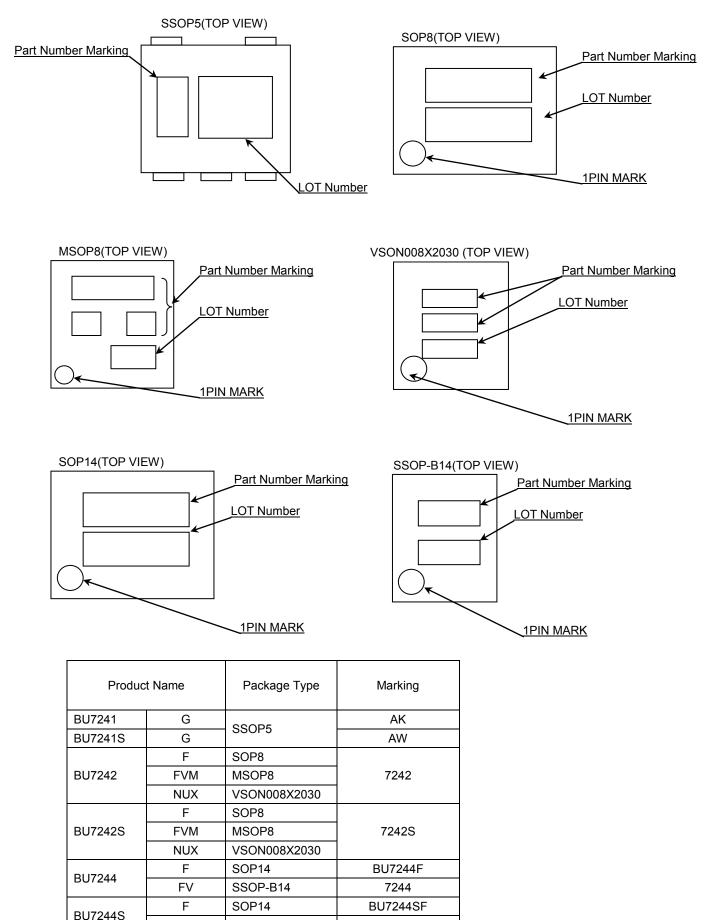
19. Decupling Capacitor

Insert the decupling capacitance between VDD and VSS, for stable operation of operational amplifier.

20. Radiation Land

The VSON008X2030 package has a radiation land in the center of the back. Please connect to VSS potenital or don't connect to other terminal.

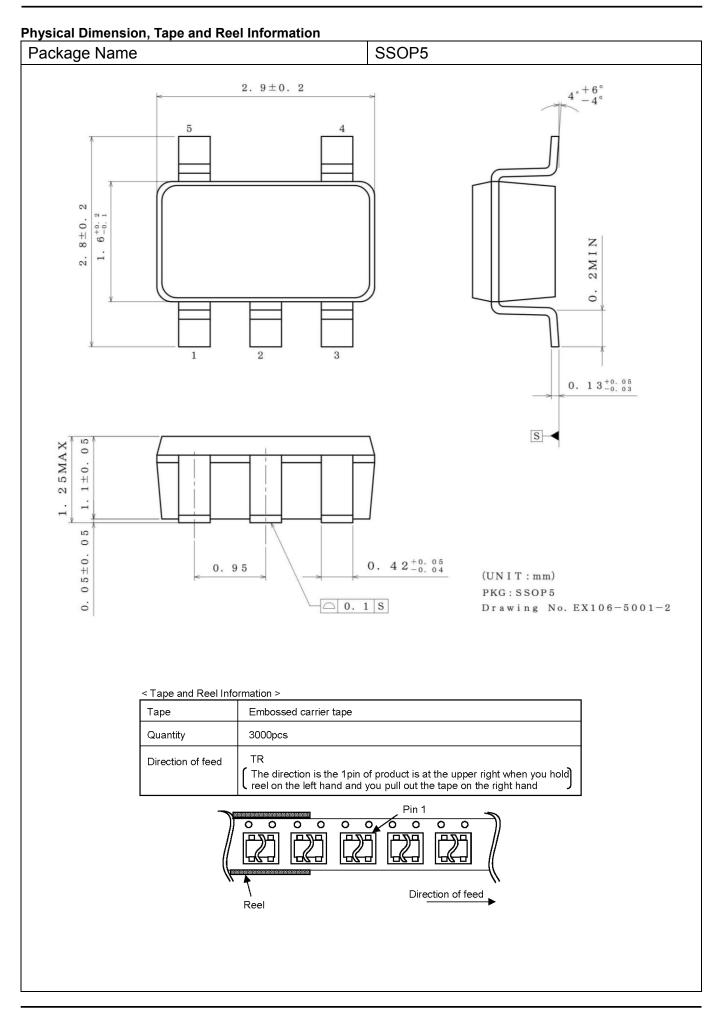
Marking Diagram

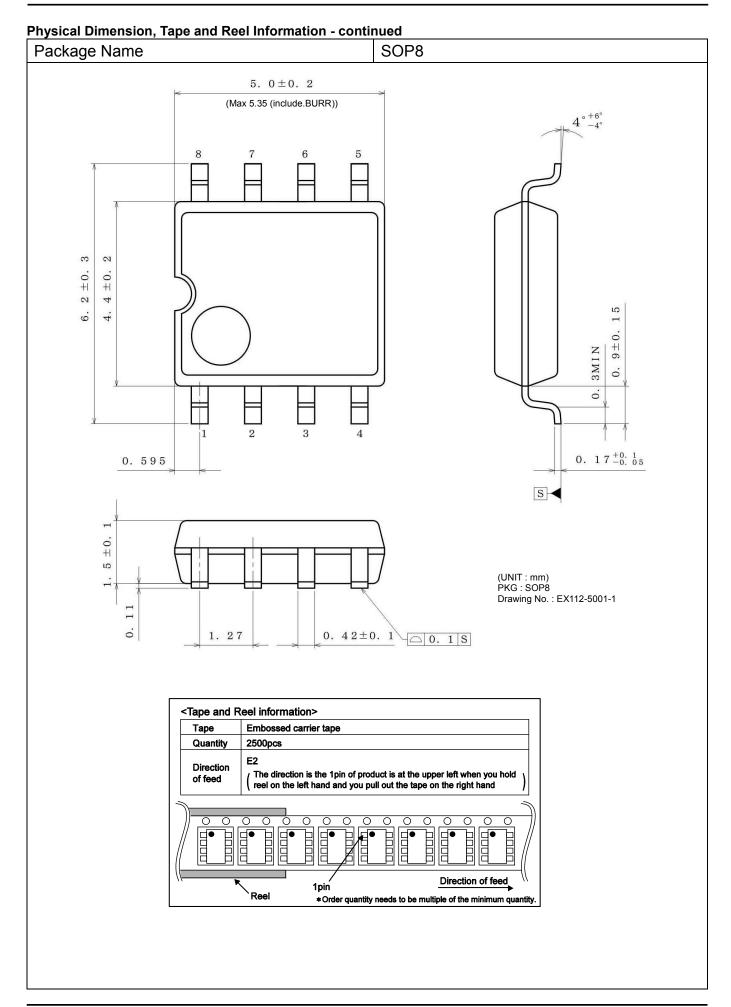


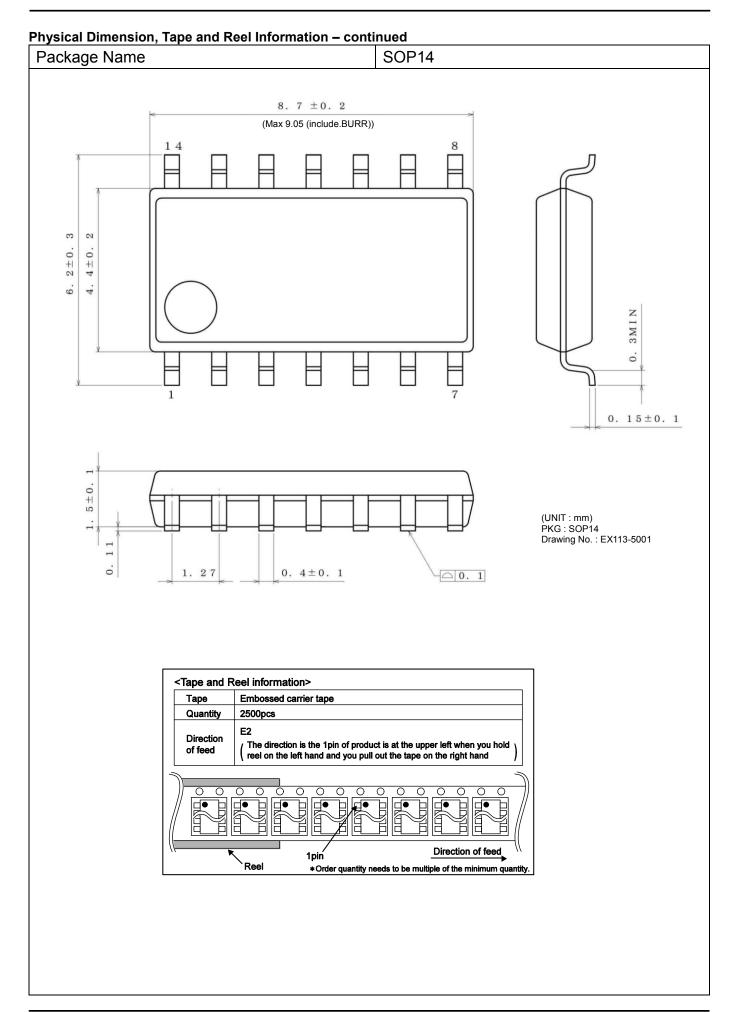
7244S

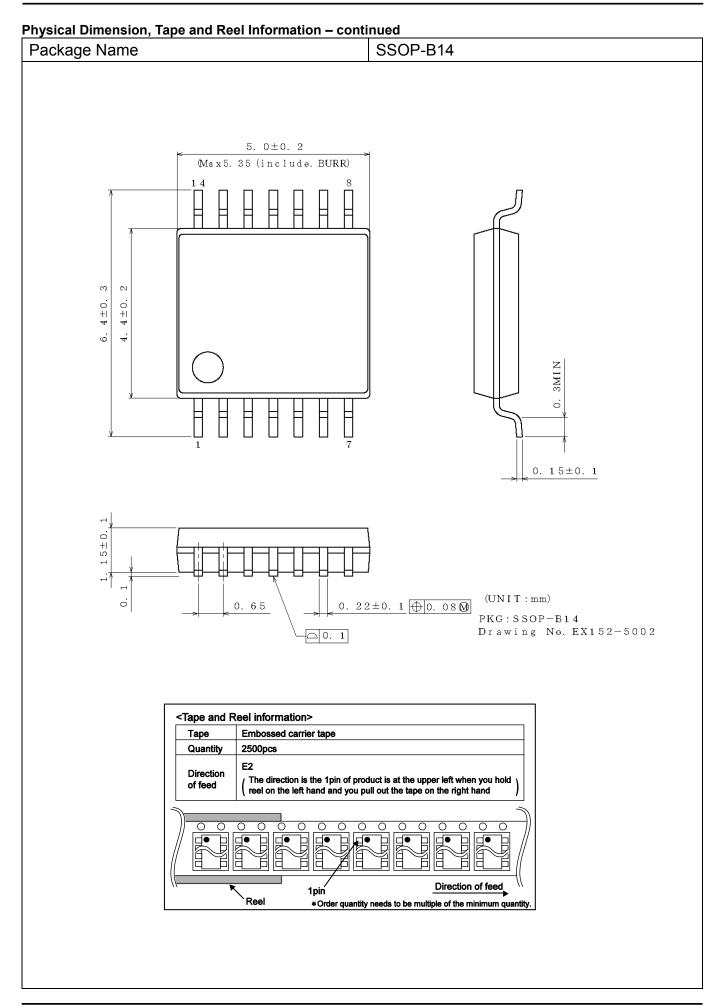
SSOP-B14

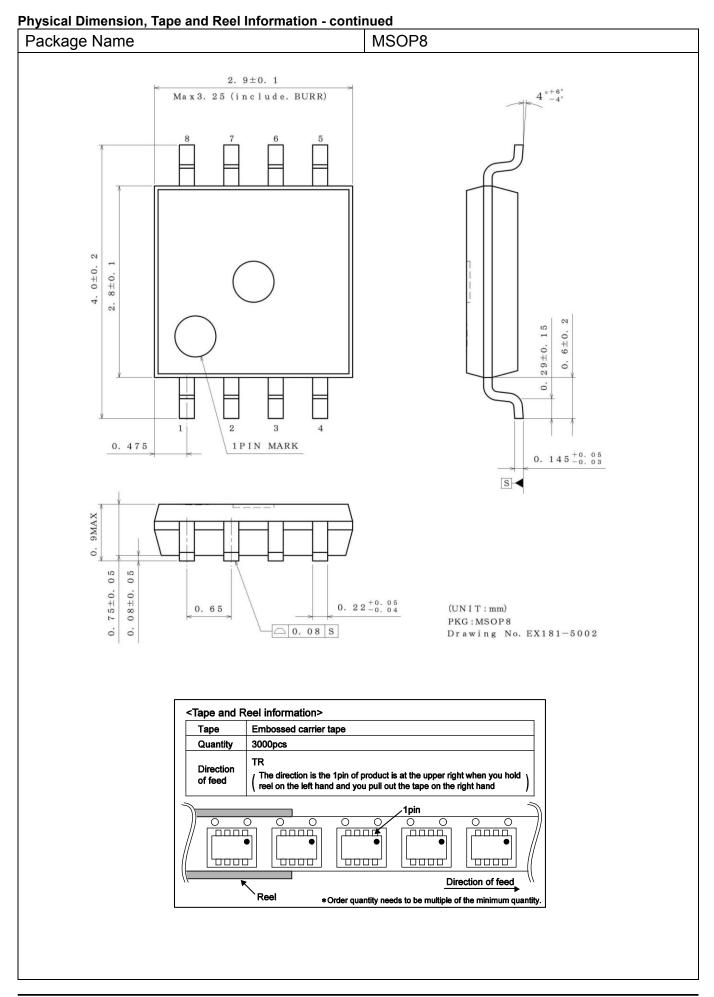
FV









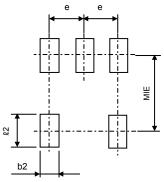


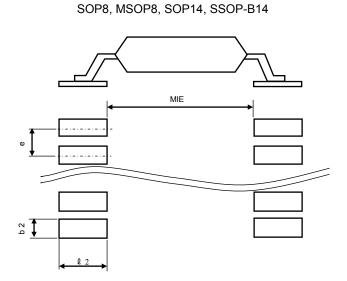
ckage Name	VSON008X2030
	2. 0 ± 0.1
	0±0. 1
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	Q
	1PIN MARK
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	o
CO	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$
-	
0 + *	8 ± 0. 4 ± 0.
	0. 25 $0. 25^{+0.05}_{-0.04}$
	(UNIT:mm) PKG:VSON008X2030
	Drawing No. EX187-5001
<tane and="" rev<="" td=""><td>el information></td></tane>	el information>
	Embossed carrier tape
Direction	4000pcs
of feed ((The direction is the 1pin of product is at the upper right when you hold) reel on the left hand and you pull out the tape on the right hand
	1pin Direction of feed
	Reel *Order quantity needs to be multiple of the minimum quantity.

Land Pattern Data

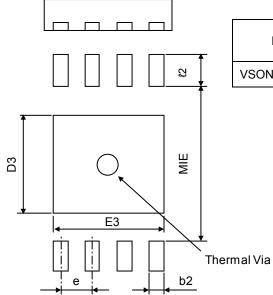
			All dim	ensions in mm
PKG	Land pitch e	Land space MIE	Land length ≧ℓ 2	Land width b2
SSOP5	0.95	2.4	1.0	0.6
SOP8 SOP14	1.27	4.60	1.10	0.76
SSOP-B14	0.65	4.60	1.20	0.35
MSOP8	0.65	2.62	0.99	0.35
VSON008X2030	0.50	2.20	0.70	0.27







VSON008X2030



PKG	Radiation	Radiation Land Width	Thermal Via		
PKG	Land Length D3	E3	Pitch	Diameter	
VSON008X2030	1.2	1.6	-	Ф0.3	

Revision History

	Date	Revision	Changes
24.Sep.2013 001		001	New Release
	18.Apr.2014	002	Addition of BU7244FV,BU7244SFV in the Pin Configuration(Page 2.)
	03.Dec.2014	003	Modify the Title of Figure. 7,9,30,34,54,55

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	JAPAN	USA	EU	CHINA
ľ	CLASSⅢ	CLASSⅢ	CLASS II b	
	CLASSⅣ	CLASSII	CLASSⅢ	CLASSⅢ

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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
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- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
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